

VOLTAGE DETECTOR

AZ70XX

General Description

The AZ70XX series ICs are under voltage detectors with a built in voltage threshold and low power consumption. The AZ70XX are specifically designed to accurately monitor power supplies.

The AZ70XX use a precision on-chip voltage reference and a comparator to measure the input operating voltage. These ICs can accurately reset the system after detecting voltage at the time of switching power on and instantaneous power off in various CPU systems and other logic systems. The detect voltage thresholds are 2.3V/2.5V/2.7V/2.9V/3.1V/3.3V/4.2V/4.5V for AZ7023/25/27/29/31/33/42/45 respectively. Built in hysteresis helps to prevent erratic operation in the presence of noise.

The AZ70XX series are available in 2 standard packages: TO-92 (bulk or ammo packing) and SOT-89.

Features

- Low Current Consumption:
 $I_{CCL}=300\mu A$ Typical
 $I_{CCH}=30\mu A$ Typical
- Low Minimum Operating Voltage for Output Resetting: 0.8V Typical
- Built in Hysteresis Voltage: 50mV Typical
- Open Collector Output
- Extended Temperature Range: -40 to 85°C

Applications

- Low Battery Voltage Detector
- Power Fail Indicator
- Processor Reset Generator
- Battery Backup Control
- Home Electric Appliances



Figure 1. Package Types of AZ70XX

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Pin Configuration

Z Package
(TO-92(Bulk Packing))



Z Package
(TO-92(Ammo Packing))



R Package
(SOT-89)

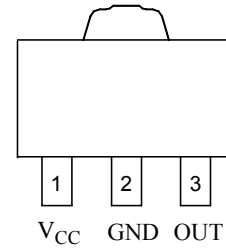


Figure 2. Pin Configuration of AZ70XX (Top View)

Functional Block Diagram



Figure 3. Functional Block Diagram of AZ70XX

**VOLTAGE DETECTOR****AZ70XX****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	-0.3 to 20	V
Power Dissipation (Package Limitations, $T_A=25^{\circ}\text{C}$)	P_D	TO-92 Package: 400	mW
		SOT-89 Package: 500	
Operating Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to 150	$^{\circ}\text{C}$

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}		18	V
Operating Temperature Range	T_A	-40	85	$^{\circ}\text{C}$



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Electrical Characteristics

T_A=25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Detect Voltage	V _{DET}	R _L =200Ω (Note 2) V _{OL} ≤ 0.4V	AZ7023R/Z	2.15	2.3	2.45	V
			AZ7025R/Z	2.35	2.5	2.65	
			AZ7027R/Z	2.55	2.7	2.85	
			AZ7029R/Z	2.75	2.9	3.05	
			AZ7031R/Z	2.95	3.1	3.25	
			AZ7033R/Z	3.15	3.3	3.45	
			AZ7042R/Z	4.05	4.2	4.35	
			AZ7045R/Z	4.35	4.5	4.65	
Low-level Output Voltage	V _{OL}	V _{CC} =V _{DET} (min)-0.05V R _L =200Ω (Note 2)			0.4	V	
Output Leakage Current	I _{OH}	V _{CC} =18V			0.1	μA	
Hysteresis Voltage	V _{HYS}	R _L =200Ω (Note 2)	30	50	100	mV	
Detect Voltage Temperature Coefficient	$\frac{\Delta V_{DET}}{V_{DET}} \times \Delta T$	R _L =200Ω (Note 2)		±0.01		% /°C	
Circuit Current at On Time	I _{CCL}	V _{CC} =V _{DET} (min)-0.05V		300	500	μA	
Circuit Current at Off Time	I _{CCH}	V _{CC} =5.25V		30	50	μA	
Minimum Operating Voltage	V _{OPR}	R _L =200Ω (Note 2) V _{OL} ≤ 0.4V		0.8		V	
“L” Transmission Delay Time	tpHL	V _{CC} changed from 5.25V to V _{DET} (min)-0.05V, R _L =1.0KΩ, C _L =100p (Note 3)		10		μs	
“H” Transmission Delay Time	tpLH	V _{CC} changed from V _{DET} (min)-0.05V to 5.25V, R _L =1.0KΩ, C _L =100p (Note 3)		15		μs	
Output Current at On Time	I _{OL I}	V _{CC} =V _{DET} (min)-0.05V T _A =25°C (Note 4)	20			mA	
	I _{OL II}	V _{CC} =V _{DET} (min)-0.05V T _A =-40 to 85 °C (Note 4)	16				
Thermal Resistance (Junction to Case)	θ _{JC}	TO-92		72		°C/W	
		SOT-89		74			

Note 2: See test circuit 1 and Figure 12.

Note 3: See test circuit 2 and Figure 12.

Note 4: See test circuit 3. Adjusting the regulative power source until the reading value of voltage meter V is 0.4V, the reading value of current meter A is defined as "Output Current at On Time".

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Electrical Characteristics (Continued)



Figure 4. Test Circuit 1



Figure 5. Test Circuit 2



Figure 6. Test Circuit 3



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Typical Performance Characteristics



Figure 7. Detect Voltage vs. Temperature



Figure 8. Minimum Operating Voltage vs. Temperature



Figure 9. Output Current at On Time vs. Temperature



Figure 10. Low-level Output Voltage vs. Temperature

Typical Performance Characteristics (Continued)

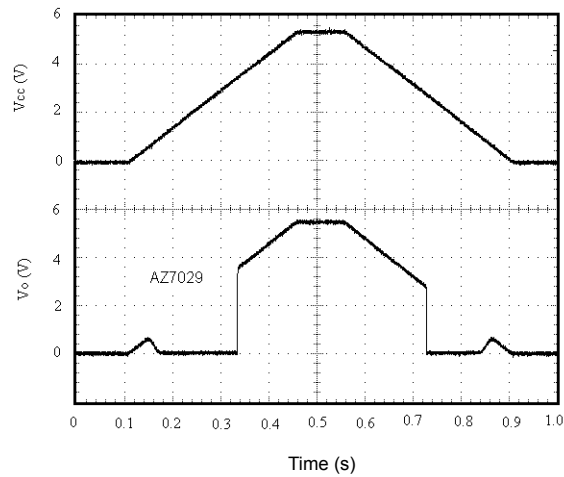


Figure 11. Output Voltage Dynamic Response when V_{CC} Increases and Decreases

Operating Diagram

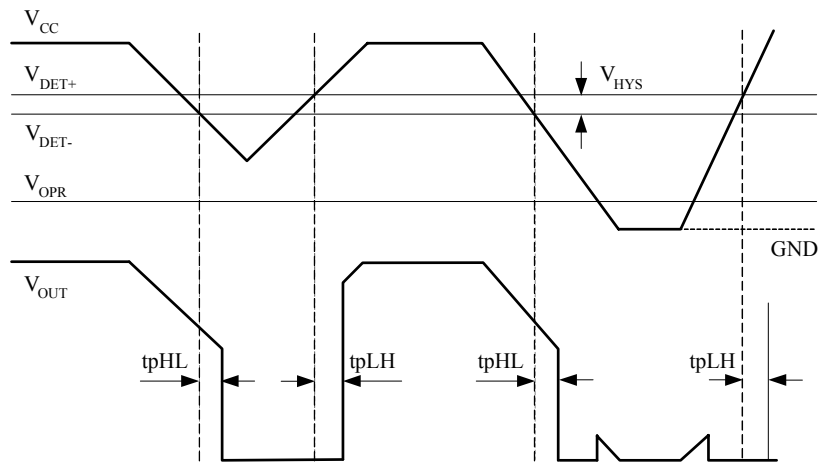


Figure 12. AZ70XX Timing Waveform (Note 5)

Note 5: Detect voltage: V_{DET-}

Hysteresis voltage (V_{HYS}): $V_{DET+} - V_{DET-}$

Release voltage: V_{DET+}

Minimum operating voltage: V_{OPR}

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Operating Diagram (Continued)

Figure 12 is a typical timing waveform for AZ70XX. In normal steady-state operation when $V_{CC} > V_{DET-}$, the output will be in a logic high state and V_{OUT} is dependent upon the voltage that the pull-up resistor connected to.

Here is some explanations for AZ70XX's operation.

1. When the input voltage V_{CC} falls below V_{DET-} , the output will pull down to logic low after a delay time of t_{pHL} . In general, at rated output current and V_{CC} , V_{OUT} can be pulled down to a voltage as low as within 0.4V from GND. (See the Electrical Characteristics section). The voltage level V_{DET-} means the detect voltage.

2. The output, V_{OUT} , will stay valid until V_{CC} falls below the minimum operating voltage, V_{OPR} (0.8V

typical). Below minimum operating voltage, the output is undefined.

3. During power-up, V_{OUT} will remain undefined until V_{CC} rises above V_{OPR} , at which time the output will become valid. V_{OUT} will be in its active low state while $V_{OPR} < V_{CC} < V_{DET+}$ ($V_{DET+} = V_{DET-} + V_{HYS}$). V_{DET+} is the release voltage. V_{HYS} means the hysteresis voltage and is the difference voltage between the V_{DET+} and V_{DET-} .

4. When V_{CC} rises above V_{DET+} , the output will be in its inactive state. After a delay time of t_{pLH} , V_{OUT} will be in its logic high state .

Typical Applications



Figure 13. Low Voltage Indicator



Figure 14. CPU Resetting Circuit



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Mechanical Dimensions

TO-92(Bulk Packing)

Unit: mm(inch)





VOLTAGE DETECTOR

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Mechanical Dimensions (Continued)

TO-92(Ammo Packing)

Unit: mm(inch)





VOLTAGE DETECTOR

AZ70XX

Mechanical Dimensions (Continued)

SOT-89

Unit: mm(inch)





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